

DC Input 4-Pin Phototransistor Optocoupler

Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- External Creepage ≥ 7.4mm
- Distance Through Isolation ≥ 0.4mm
- Spatial Distance ≥ 7.5mm (S/SL Type)
- Spatial Distance ≥ 8.0mm (M/SLM Type)
- Operating Temperature range 55 °C to 110 °C
- Regulatory Approvals
 - UL UL1577 (E364000)
 - VDE EN60747-5-5(VDE0884-5)
 - CQC GB4943.1, GB8898
 - IEC60065, IEC60950

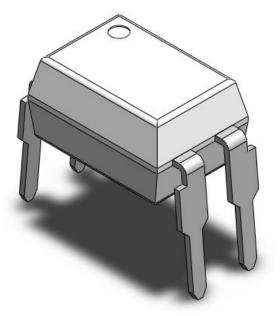
Description

The CT817 series consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead DIP package different lead forming options.

Applications

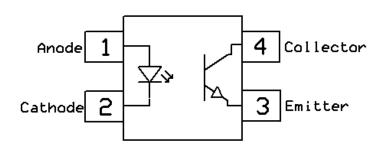
- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline



Note: Different lead forming options available. See package dimension.

Schematic





DC Input 4-Pin Phototransistor Optocoupler

Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage (AC, 1 minute)	5000	V _{RMS}	
Ртот	Total power dissipation	200	mW	
Topr	Operating temperature	-55 ~ +110	°C	
Tstg	Storage temperature	-55 ~ +150	°C	
TsoL	Soldering temperature	260	°C	
Emitter				
I _F	Forward current	60	mA	
I _F (TRANS)	Peak transient current (≤1µs P.W,300pps)	1	Α	
VR	Reverse voltage	6	V	
PD	Emitter power dissipation	100	mW	
Rth _{J-A}	Thermal Resistance Junction-Ambient	350	°C/W	
TJ	Junction temperature	125	°C	
Detector				
P _D	Detector power dissipation	150	mW	
Bvceo	Collector-Emitter Breakdown Voltage	35	V	
B _{VECO}	Emitter-Collector Breakdown Voltage	6	V	
Ic	Collector Current	50	mA	



DC Input 4-Pin Phototransistor Optocoupler

Electrical Characteristics $T_A = 25$ °C (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I _F =10mA	-	1.24	1.4	V	
I _R	Reverse Current	V _R = 6V	-	-	5	μΑ	
Cin	Input Capacitance	f= 1MHz	-	10	30	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
Bvceo	Collector-Emitter Breakdown	I _C = 100μA	35	-	-	V	
B _{VECO}	Emitter-Collector Breakdown	I _E = 100μA	6	-	-	V	
ICEO	Collector-Emitter Dark Current	V _{CE} = 20V, I _F =0mA	-	-	100	nA	

Transfer Characteristics

Symbol	Parameters		Test Conditions	Min	Тур	Мах	Units	Notes
	Current Transfer Ratio CT8176	CT817	IF= 5mA, VcE= 5V	50	-	600	%	
		CT817A		80	-	160		
CTR		CT817B		130	-	260		
		CT817C		200	-	400		
		CT817D		300	-	600		
V	Collector-Emitter Saturation		I _F = 20mA, I _C = 1mA		0.1	0.2	V	
V _{CE(SAT)}	Voltage		IF= 20IIIA, IC= IIIIA	-	0.1	0.2	V	
Rıo	Isolation Resistance		V _{IO} = 500V _{DC}	5x10 ¹⁰	-	-	Ω	
Сю	Isolation Capacitance		f= 1MHz	-	0.25	1	pF	

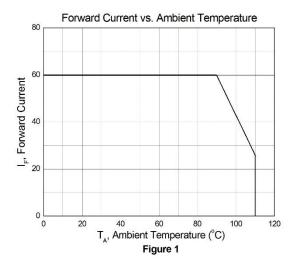
Switching Characteristics

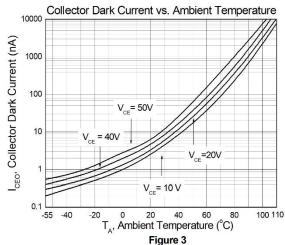
Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
t _r	Rise Time	I _C = 2mA, V _{CE} = 2V	-	6	18	0	
t _f	Fall Time	R _L = 100Ω	-	8	18	μS	

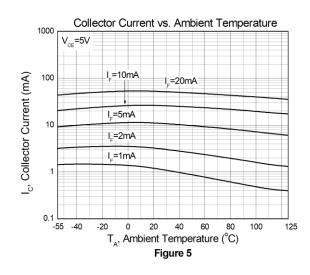


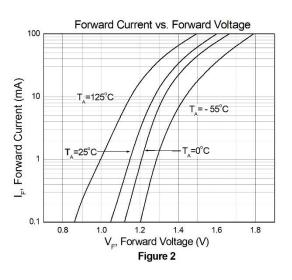


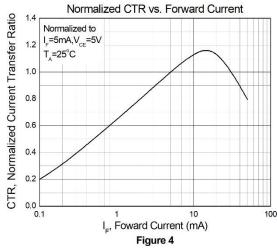
Typical Characteristic Curves

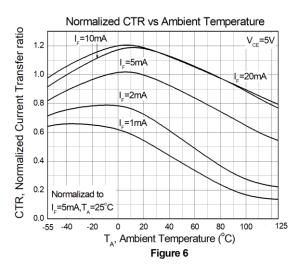






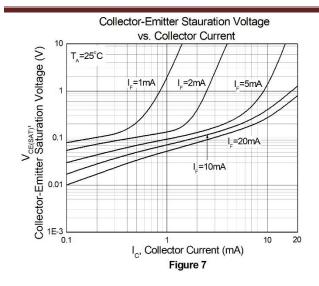


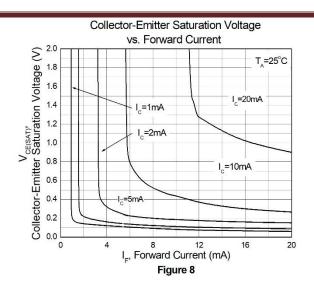


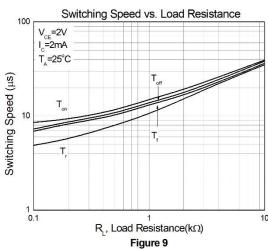


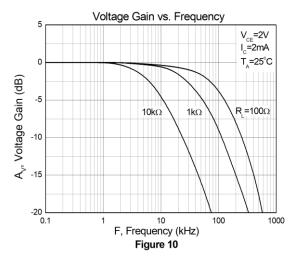


DC Input 4-Pin Phototransistor Optocoupler











Test Circuit

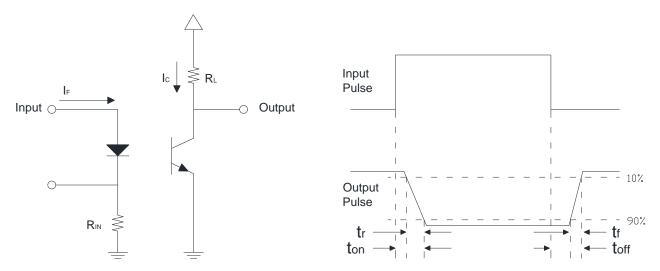


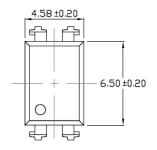
Figure 12: Switching Time Test Circuits

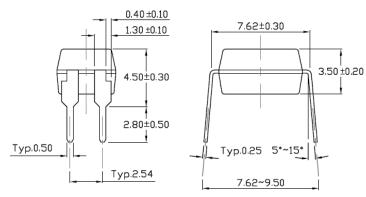




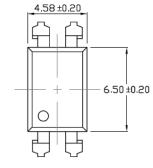
Package Dimension Dimensions in mm unless otherwise stated

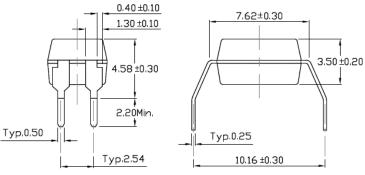
Standard DIP - Through Hole





Gullwing (400mil) Lead Forming – Through Hole (M Type)

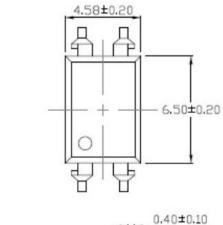


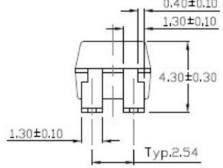


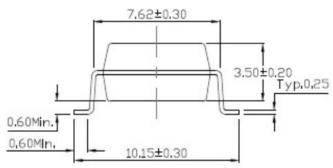




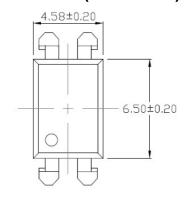
Surface Mount Lead Forming (S Type)

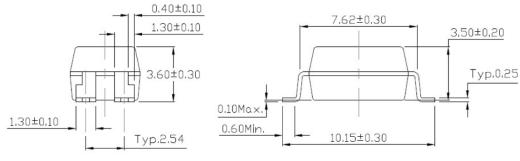






Surface Mount (Low Profile) Lead Forming (SL Type)

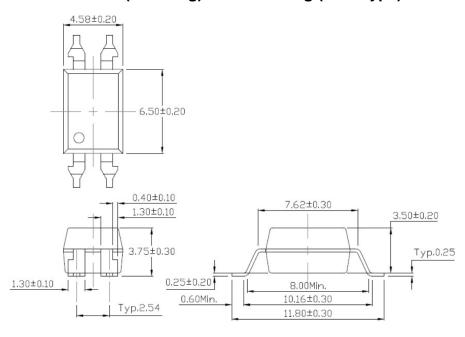






DC Input 4-Pin Phototransistor Optocoupler

Surface Mount (Gullwing) Lead Forming (SLM Type)

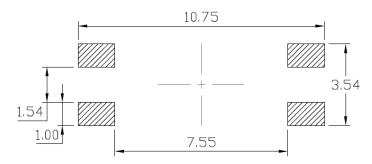




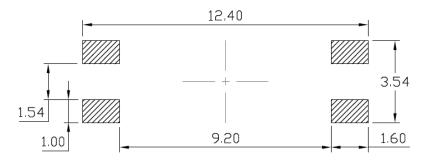


Recommended Solder Mask Dimensions in mm unless otherwise stated

Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming



Marking Information



* : 第三行打 * 點為銅支架材質,不打點為鐵支架材質。

Note:

CT : Denotes "CT Micro"

817 : Part Number

R : CTR Rank

V : VDE Option

Y : Fiscal Year

WW : Work Week

K : Manufacturing Code





Ordering Information

CT817X(V)(Y)(Z)-HG

X = Part No. (X=A, B, C, D or None)

V = VDE Option (V or None)

Y = Lead form option (S, SL, M, SLM or none)

Z = Tape and reel option (T1, T2, T3, T4 or none)

H = Lead frame option (H: Iron, None: Copper)

G= Material option (G: Green, None: Non-green)

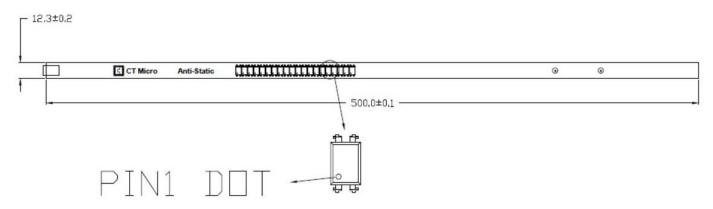
Option	Description	Quantity
None	Standard 4 Pin Dip	100 Units/Tube
М	Gullwing (400mil) Lead Forming	100 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1500 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1500 Units/Reel
S(T3)	Surface Mount Lead Forming – With Option 3 Taping	1000 Units/Reel
S(T4)	Surface Mount Lead Forming – With Option 4 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming- With Option 1 Taping	1500 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1500 Units/Reel
SL(T3)	Surface Mount (Low Profile) Lead Forming- With Option 3 Taping	1000 Units/Reel
SL(T4)	Surface Mount (Low Profile) Lead Forming – With Option 4 Taping	1000 Units/Reel
SLM(T1)	Surface Mount (Gullwing) Lead Forming– With Option 1 Taping	1500 Units/Reel
SLM(T2)	Surface Mount (Gullwing) Lead Forming – With Option 2 Taping	1500 Units/Reel



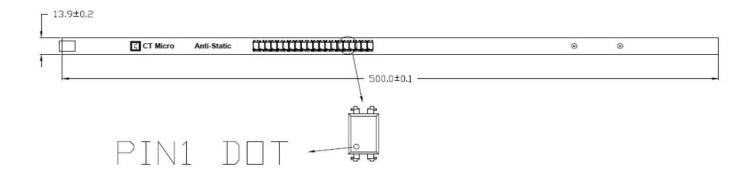


Carrier Specifications Dimensions in mm unless otherwise stated

Tube Option Standard DIP



Tube Option M Type



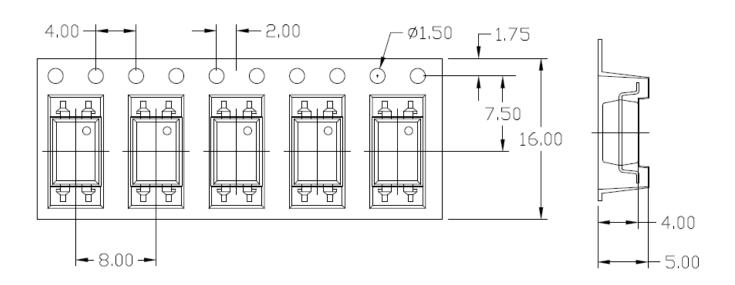


DC Input 4-Pin Phototransistor Optocoupler

Carrier Tape Specifications Dimensions in mm unless otherwise stated

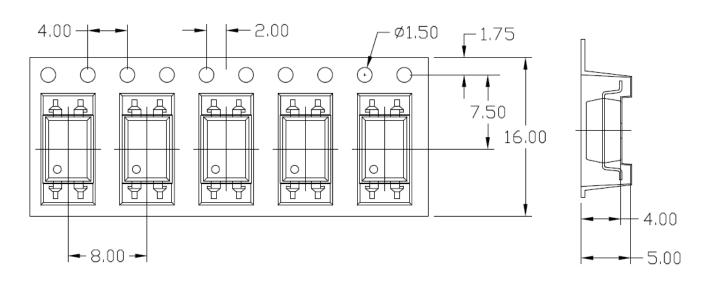
Option S(T1) & SL(T1)

Input Direction



Option S(T2) & SL(T2)

Input Direction

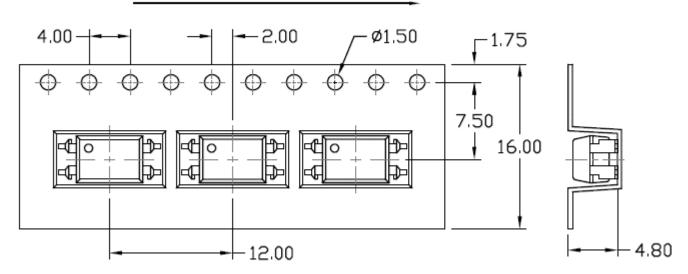




DC Input 4-Pin Phototransistor Optocoupler

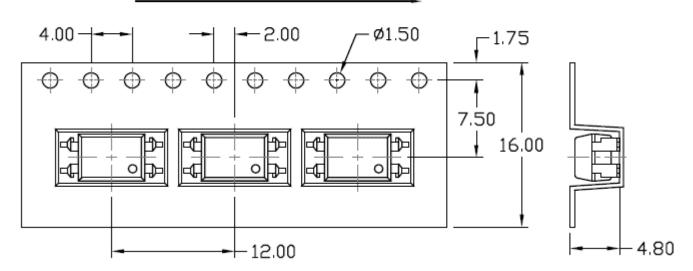
Option S(T3) & SL(T3)

Input Direction



Option S(T4) & SL(T4)

Input Direction

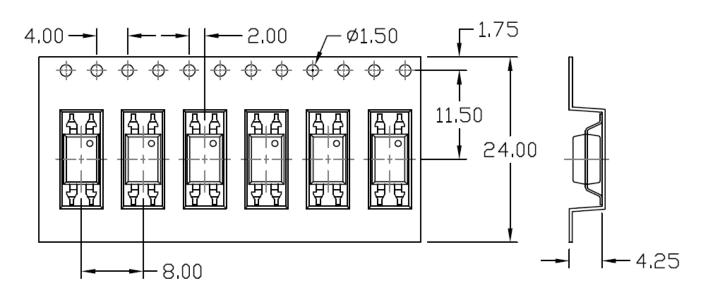






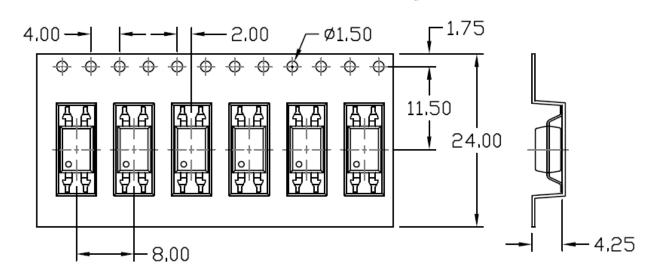
Option SLM(T1)

Input Direction



Option SLM(T2)

Input Direction







Wave soldering (follow the JEDEC standard JESD22-A111)

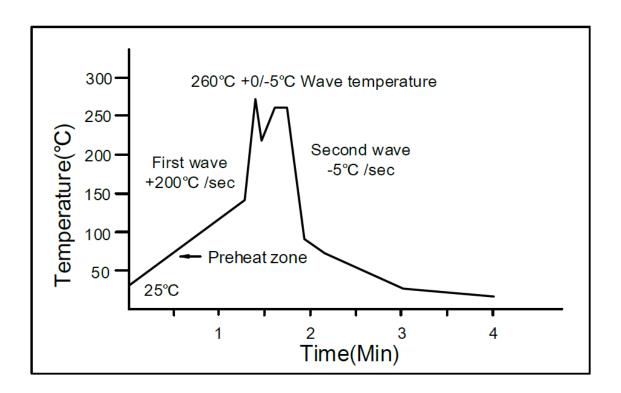
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.



Iron soldering (follow the standard MIL-STD 202G, Method 210F)

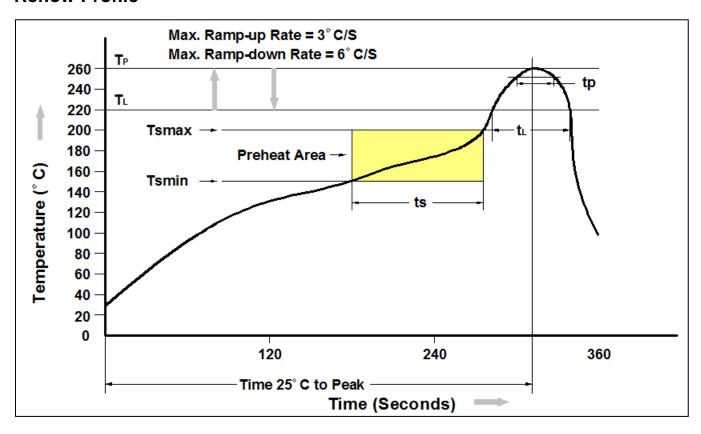
Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: 350+±10°C

Time: 5 sec max.



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



DC Input 4-Pin Phototransistor Optocoupler

DISCLAIMER

CT MICRO RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. CT MICRO DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

DISCOLORATION MIGHT OCCUR ON THE PACKAGE SURFACE AFTER SOLDERING, REFLOW OR LONG TERM USE. THIS DOES NOT IMPACT THE PRODUCT PERFORMANCE NOR THE PRODUCT RELIABILITY.

CT MICRO ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT EXPRESS WRITTEN APPROVAL OF CT MICRO INTERNATIONAL CORPORATION.

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instruction for use provided in the labelling, can be reasonably expected to result in significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

单击下面可查看定价,库存,交付和生命周期等信息

>>CT-MICRO(兆龙科技)